

# SWITCH MODE POWER RECTIFIERS D PAK SURFACE MOUNT POWER PACKAGE

The D PAK Power rectifier employs the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art devices have the following features:

- \* Low Forward Voltage
- \* Low Switching noise
- \* High Surge Capacity
- \* Guarantee Reverse Avalanche
- \* Guard-Ring for Stress Protection
- \* Lower Power Loss & High efficiency
- \* 150 Operating Junction Temperature
- \* Lower Stored Charge Majority Carrier Conduction
- \* Similar Size to the industry Standard TO-251 Package
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- \* Marking: S1630T-S1645T
- \* Weight: 0.011 ounce, 0.295 gram

### **MAXIMUM RATINGS**

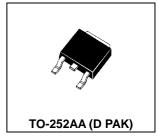
Characteristic	Symbol	SBD				Unit
Characteristic		1630CT	1635CT	1640CT	1645CT	Oill
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	30	35	40	45	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	21	25	28	32	٧
Average Rectifier Forward Current ( per diode ) Total Device (Rated V <sub>R</sub> ), T <sub>C</sub> =100	I <sub>F(AV)</sub>	10 20			Α	
Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz)	I <sub>FM</sub>	20			А	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I <sub>FSM</sub>	175			Α	
Operating and Storage Junction Temperature Range	$T_J$ , $T_{stg}$	-65 to +150				

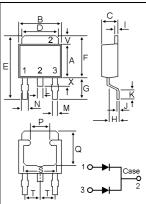
#### **ELECTRIAL CHARACTERISTICS**

Chamatariatia	Symbol	SBD				11:4
Characteristic		2030CT	2035CT	2040CT	2045CT	Unit
Maximum Instantaneous Forward Voltage ( $I_F = 10 \text{ Amp}, T_C = 25$ )	V <sub>F</sub>	0.55			٧	
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25$ ) ( Rated DC Voltage, $T_C = 125$ )	I <sub>R</sub>	0.5 20			mA	

## SCHOTTKY BARRIER RECTIFIERS

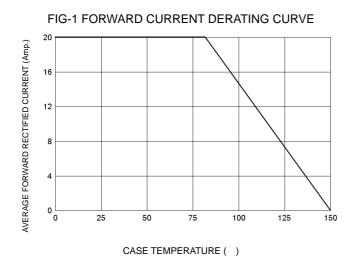
20 AMPERES 30-45 VOLTS

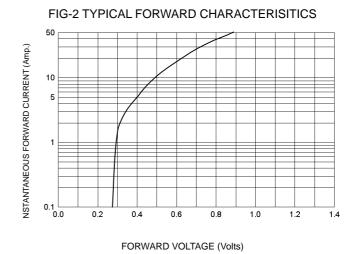


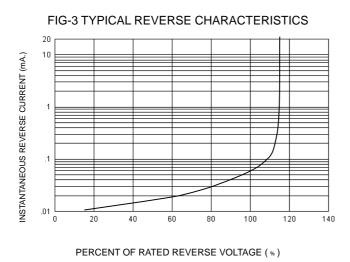


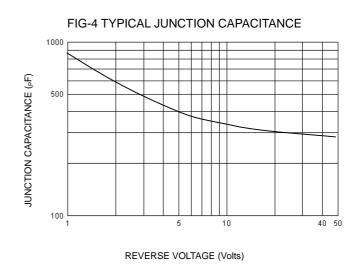
DIM	MILLIMETERS			
DIIVI	MIN	MAX		
Α	5.40	5.60		
В	6.30	6.70		
С	2.20	2.40		
D	5.20	5.50		
E	9.00	10.00		
F	6.60	7.00		
G	2.40	3.00		
Н	0.90	1.50		
- 1	0.45	0.55		
J	0.45	0.60		
K	0.90	1.50		
L	0.70	0.90		
M	0.50	0.70		
N	0.60	0.90		
Р	2.70	3.10		
Q	5.00	5.40		
S	4.80	5.20		
Т		2.30		
V	1.20	1.40		
Χ	0.80	1.20		

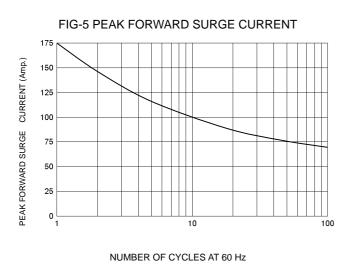
### SBD2030CT thru SBD2045CT













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